# NSN 5961-01-080-2058

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### Inclosure Material:

Metal

**Overall Length:** 

0.050 inches

## **Overall Diameter:**

Between 0.009 inches and 0.011 inches

### Internal Configuration:

Junction contact

#### Internal Junction Configuration:

Npn

## **Mounting Method:**

Press fit

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

20.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

20.00 milliamperes source cutoff current

## Power Rating Per Characteristic:

300.0 milliwatts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

#### **Test Data Document:**

01341-+2725 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

4 pin

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

## Fiig:

A110a0